

PORTABLE EQUIPMENT APPLICATION

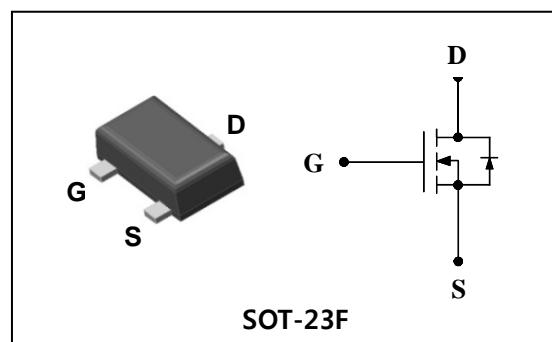
Features

- Low Voltage : $BV_{DSS}=20V$ (Min.)
- Low $V_{GS(th)}$: $V_{GS(th)}=0.6\sim1.2V$
- Small footprint due to small package
- Low $R_{DS(on)}$: $R_{DS(on)}=33m\Omega$ (Typ.)

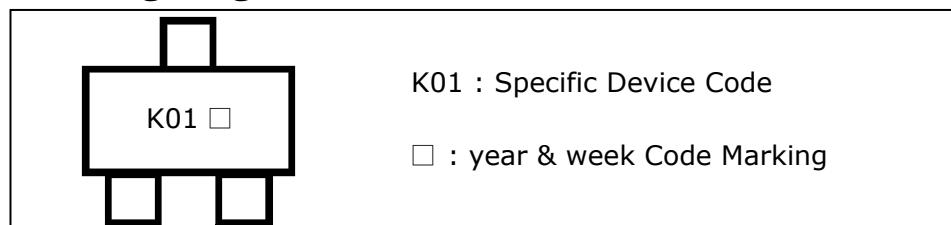
Ordering Information

Type No.	Marking	Package Code
STK001SF	K01 ① ②	SOT-23F

PIN Connection



Marking Diagram



Absolute maximum ratings ($T_A=25^\circ C$ unless otherwise noted)

Characteristic	Symbol	Rating	Unit
Drain-source voltage	V_{DSS}	20	V
Gate-source voltage	V_{GSS}	± 12	V
Drain current (DC) *	I_D	3.2	A
Drain current (Pulsed) *	I_{DM}	12.8	A
Power dissipation **	P_D	0.35	W
Avalanche current (Single) ②	I_{AS}	3.2	A
Single pulsed avalanche energy ②	E_{AS}	30	mJ
Avalanche current (Repetitive) ①	I_{AR}	3.2	A
Repetitive avalanche energy ①	E_{AR}	2.5	mJ
Junction temperature	T_J	150	$^\circ C$
Storage temperature range	T_{stg}	-55~150	

* Limited by maximum junction temperature

** Device mounted on a glass-epoxy board

Characteristic	Symbol	Typ.	Max.	Unit
Thermal resistance	$R_{th(J-A)}$	-	357	$^\circ C/W$

Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Drain-source breakdown voltage	BV_{DSS}	$I_D=250\mu\text{A}, V_{GS}=0$	20	-	-	V
Gate threshold voltage	$V_{GS(\text{th})}$	$I_D=250\mu\text{A}, V_{DS}=V_{GS}$	0.6	-	1.2	V
Drain-source cut-off current	I_{DSS}	$V_{DS}=20\text{V}, V_{GS}=0\text{V}$	-	-	1	μA
Gate leakage current	I_{GSS}	$V_{DS}=0\text{V}, V_{GS}=\pm 12\text{V}$	-	-	± 10	μA
Drain-source on-resistance ⁽⁴⁾	$R_{DS(\text{ON})}$	$V_{GS}=4.5\text{V}, I_D=1.6\text{A}$ $V_{GS}=2.5\text{V}, I_D=1.6\text{A}$	-	33	50	$\text{m}\Omega$
Forward transfer conductance ⁽⁴⁾	g_{fs}	$V_{DS}=5\text{V}, I_D=3.2\text{A}$	-	46	70	
Input capacitance	C_{iss}	$V_{GS}=0\text{V}, V_{DS}=10\text{V}, f=1\text{MHz}$	-	395	-	pF
Output capacitance	C_{oss}		-	97	-	
Reverse transfer capacitance	C_{rss}		-	44	-	
Turn-on delay time	$t_{d(on)}$	$V_{DD}=10\text{V}, I_D=3.2\text{A}$ $R_G=10\Omega$	-	3.2	-	ns
Rise time	t_r		-	2.8	-	
Turn-off delay time	$t_{d(off)}$		-	20	-	
Fall time	t_f		-	2.8	-	
Total gate charge	Q_g	$V_{DD}=10\text{V}, V_{GS}=4.5\text{V}$ $I_D=3.2\text{A}$	-	6.8	10	nC
Gate-source charge	Q_{gs}		-	0.8	1.2	
Gate-drain charge	Q_{gd}		-	0.9	1.1	

Source-Drain Diode Ratings and Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Continuous source current	I_S	Integral reverse diode in the MOSFET	-	-	0.5	A
Source current (Pulsed) ⁽¹⁾	I_{SM}		-	-	2.0	
Forward voltage ⁽⁴⁾	V_{SD}	$V_{GS}=0\text{V}, I_S=0.5\text{A}$	-	0.7	1.2	V
Reverse recovery time	t_{rr}	$I_s=3.2\text{A}, V_{DD}=10\text{V}$ $dI_S/dt=70\text{A}/\mu\text{s}$	-	24	-	ns
Reverse recovery charge	Q_{rr}		-	120	-	μC

Note :

- ① Repetitive Rating : Pulse Width Limited by Maximum Junction Temperature
- ② $L=3.0\text{mH}, I_{AS}=3.8\text{A}, V_{DD}=10\text{V}, R_G=25\Omega$
- ③ Pulse Test : Pulse width $\leq 300\text{us}$, Duty cycle $\leq 2\%$
- ④ Essentially independent of operating temperature

Electrical Characteristic Curves

Fig. 1 I_D - V_{DS}

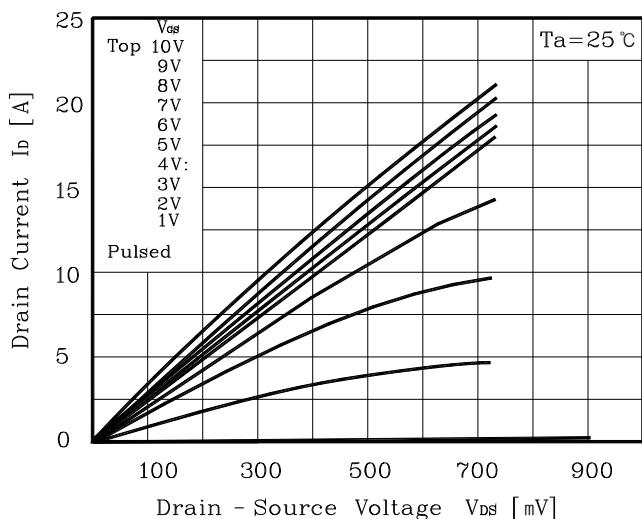


Fig. 2 I_D - V_{GS}

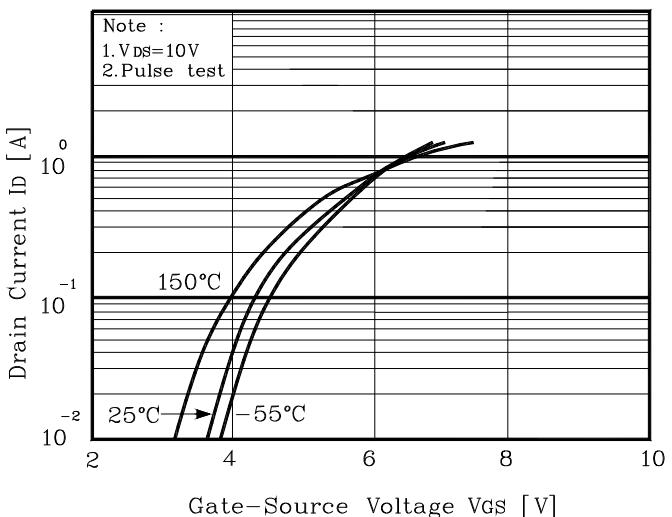


Fig. 3 $R_{DS(on)}$ - I_D

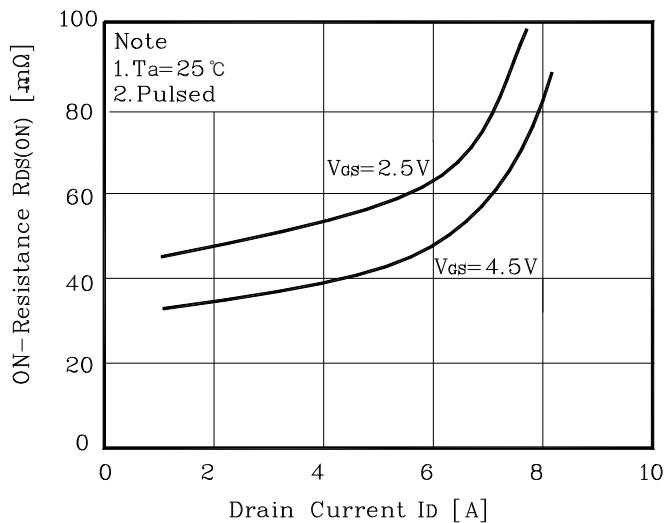


Fig. 4 I_S - V_{SD}

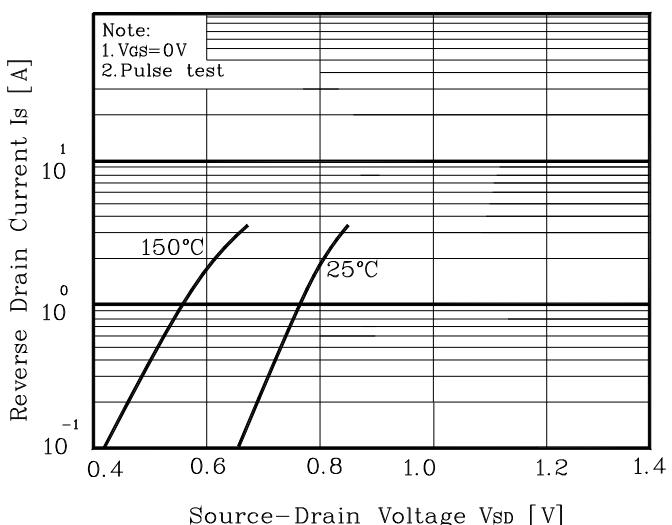


Fig. 5 Capacitance - V_{DS}

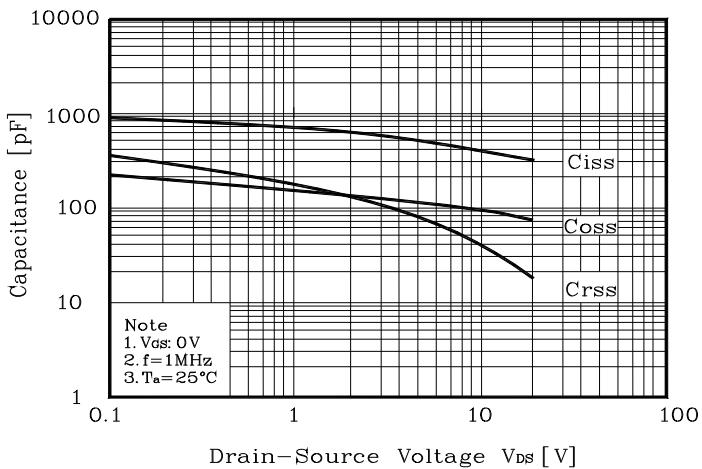


Fig. 6 V_{GS} - Q_G

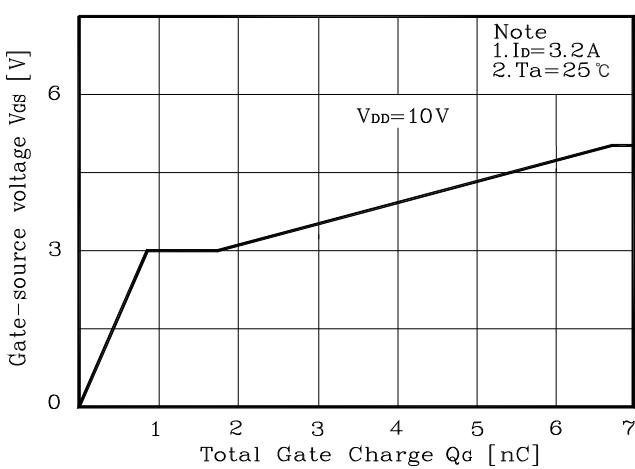


Fig. 7 V_{DSS} - T_J

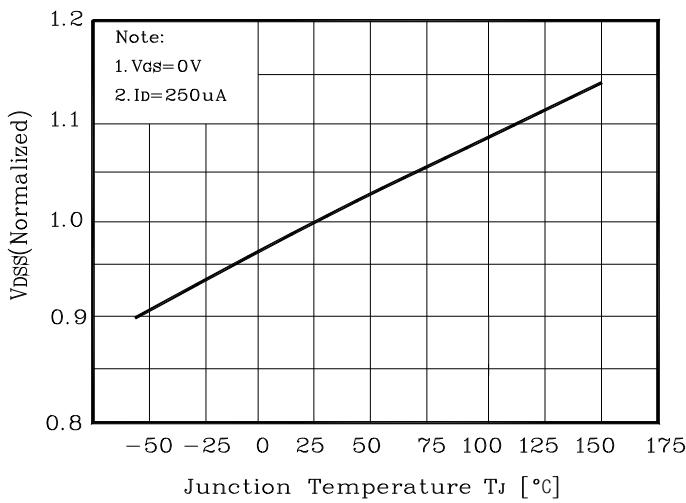


Fig. 8 $R_{DS(on)}$ - T_J

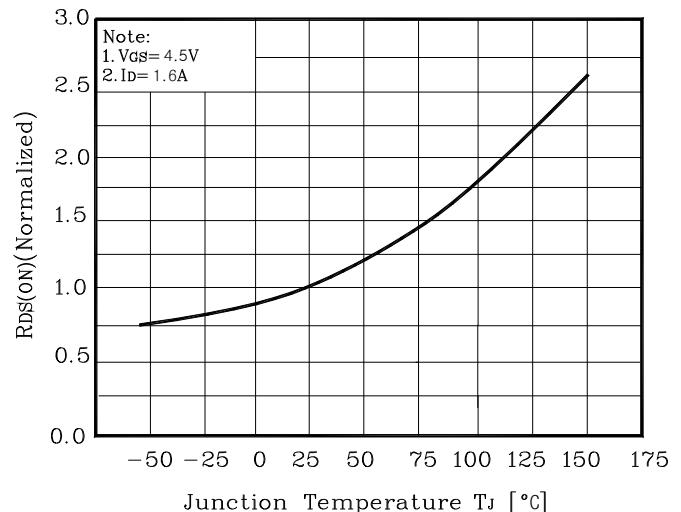


Fig. 9 I_D - T_a

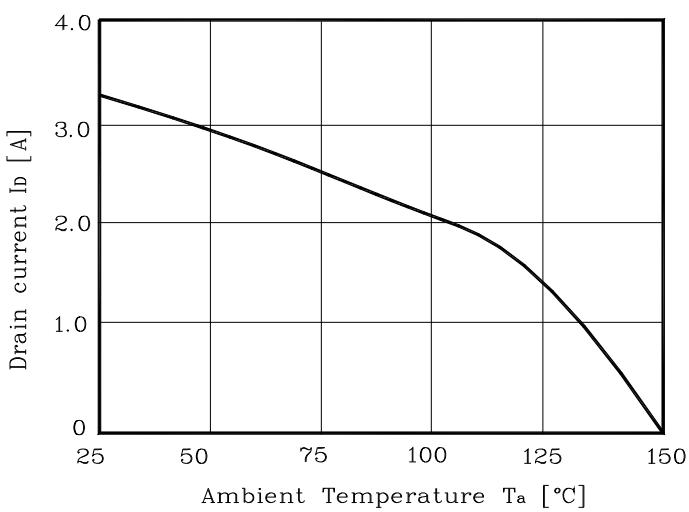


Fig. 10 Safe Operating Area

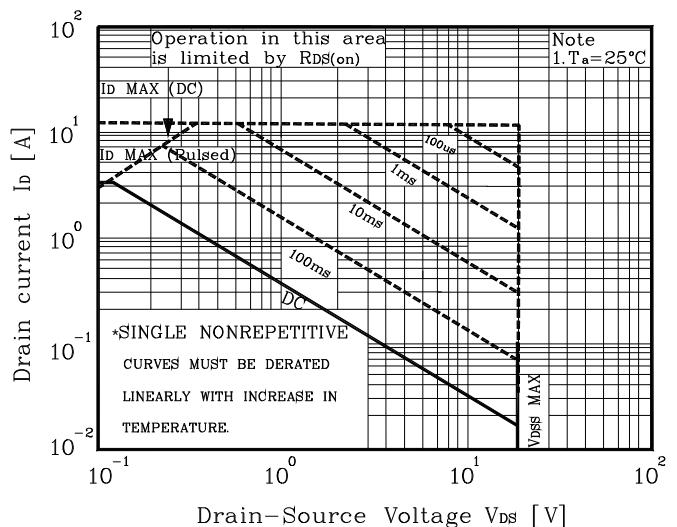


Fig. 11 Gate Charge Test Circuit & Waveform

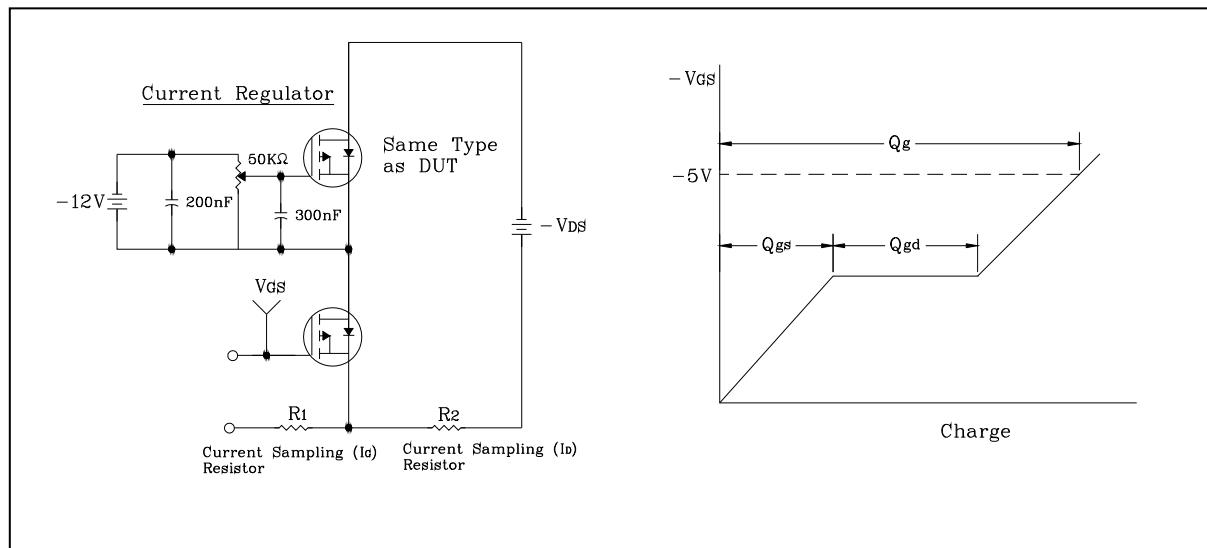


Fig. 12 Resistive Switching Test Circuit & Waveform

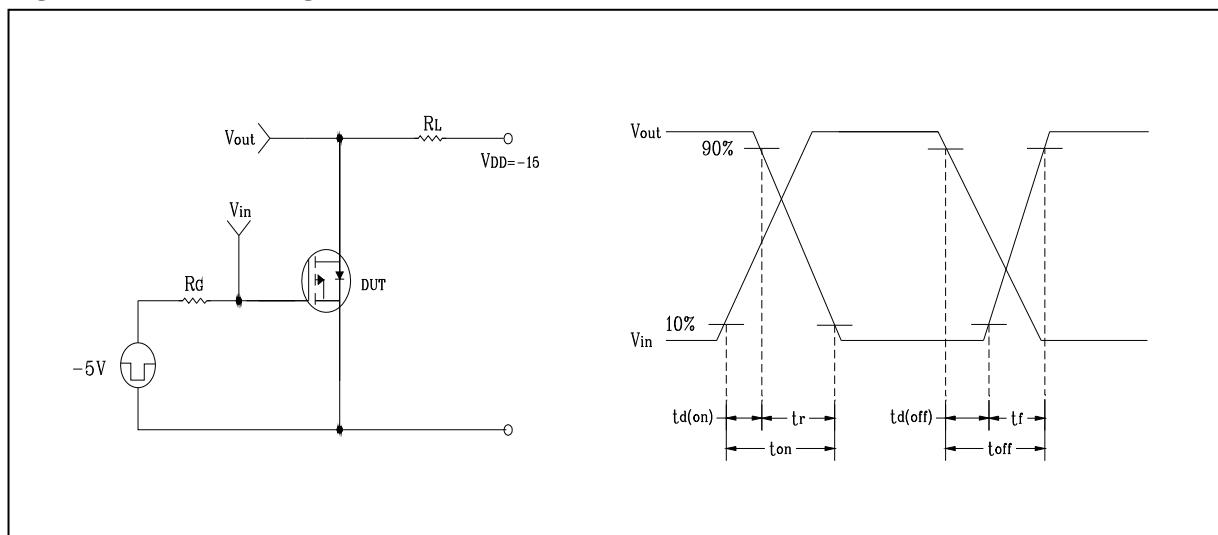


Fig. 13 E_{AS} Test Circuit & Waveform

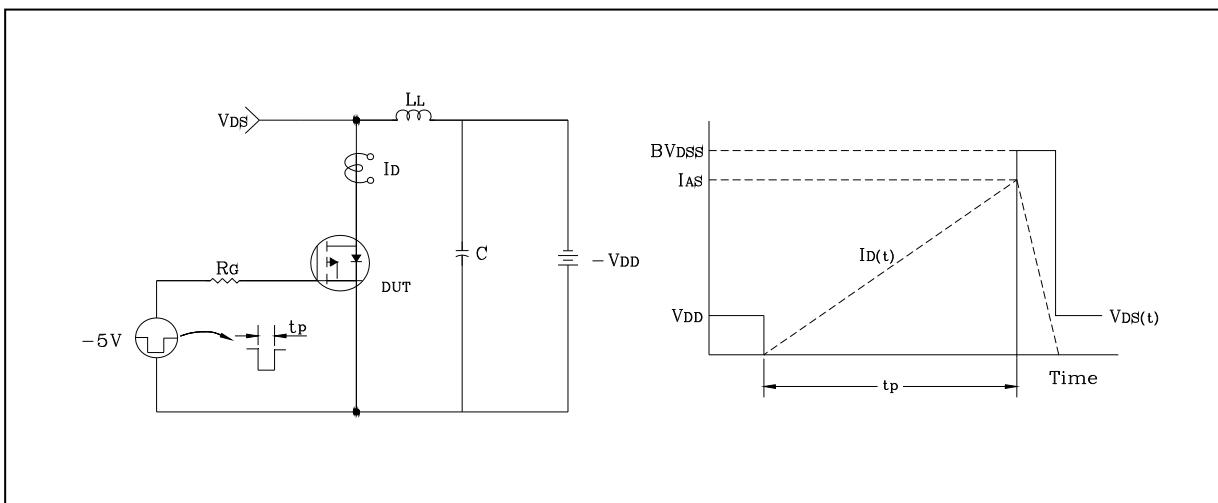
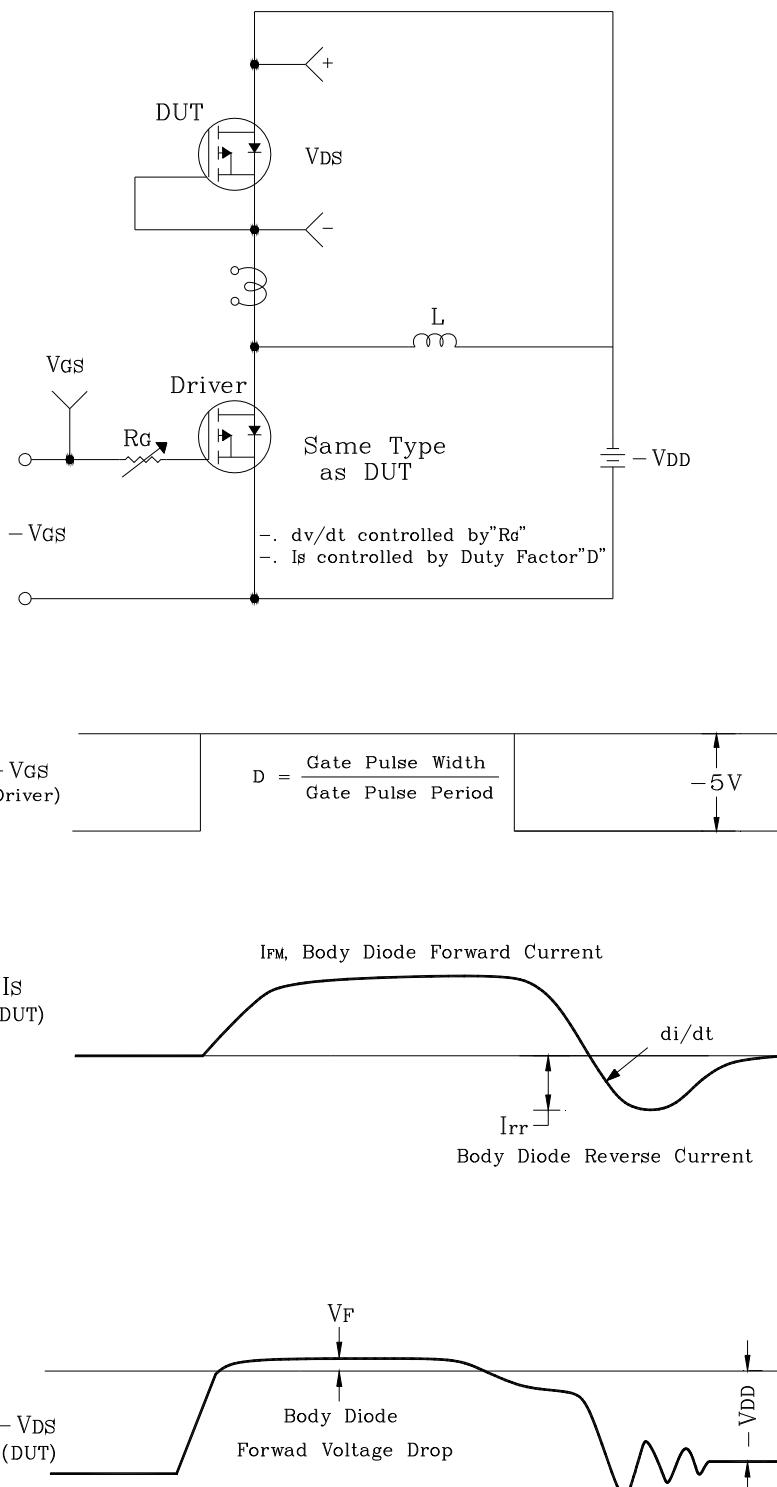
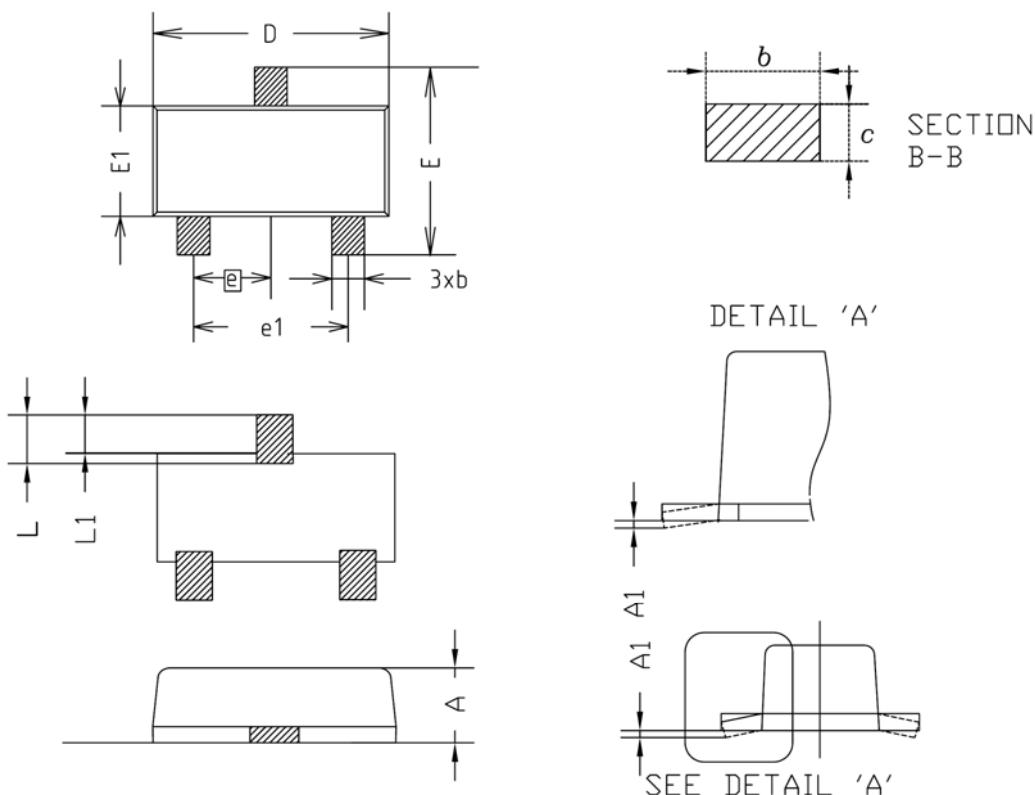


Fig. 14 Diode Reverse Recovery Time Test Circuit & Waveform

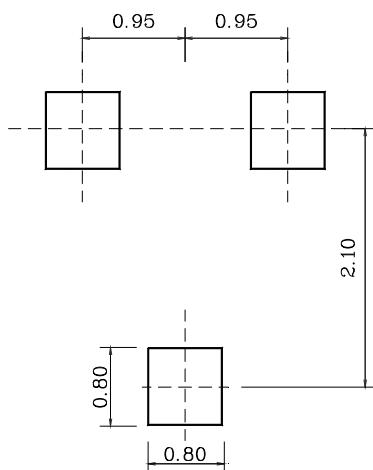


Outline Dimension

unit: mm



SYMBOL	MILLIMETER(mm)			NOTE
	MINIMUM	NOMINAL	MAXIMUM	
A	0.80	0.90	1.00	
A1	0.00	-	0.10	
b	0.35	0.40	0.45	
c	0.10	0.15	0.20	
D	2.80	2.90	3.00	
E	2.30	2.40	2.50	
E1	1.50	1.60	1.70	
e	0.95BSC			
e1	1.80	1.90	2.00	
L	0.48	0.58	0.68	
L1	0.30	-	0.50	

*** Recommended Land Pattern [unit: mm]**

The AUK Corp. products are intended for the use as components in general electronic equipment (Office and communication equipment, measuring equipment, home appliance, etc.).

Please make sure that you consult with us before you use these AUK Corp. products in equipments which require high quality and / or reliability, and in equipments which could have major impact to the welfare of human life(atomic energy control, airplane, spaceship, transportation, combustion control, all types of safety device, etc.). AUK Corp. cannot accept liability to any damage which may occur in case these AUK Corp. products were used in the mentioned equipments without prior consultation with AUK Corp..

Specifications mentioned in this publication are subject to change without notice.